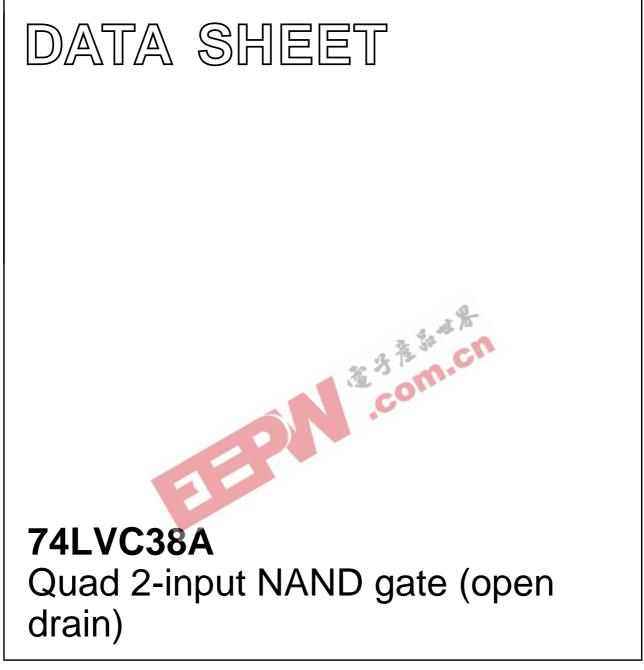
INTEGRATED CIRCUITS



Product specification Supersedes data of 2004 Mar 10 2004 Mar 22



74LVC38A

FEATURES

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Open-drain outputs
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- Specified from -40 to +85 °C and -40 to +125 °C.

DESCRIPTION

The 74LVC38A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC38A provides the 2-input NAND function.

The outputs of the 74LVC38A devices are open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = $t_f \le 2.5$ ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PZL}	propagation delay nA, nB to nY	$C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	1.7	ns
t _{PLZ}	propagation delay nA, nB to nY	$C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	2.3	ns
CI	input capacitance		4.0	pF
C _{PD}	power dissipation capacitance per gate	$V_{CC} = 3.3 V$; notes 1 and 2	5.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

TYPE NUMBER	PACKAGE							
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE			
74LVC38AD	–40 to +125 °C	14	SO14	plastic	SOT108-1			
74LVC38ADB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1			
74LVC38APW	–40 to +125 °C	14	TSSOP14	plastic	SOT402-1			
74LVC38ABQ	–40 to +125 °C	14	DHVQFN14	plastic	SOT762-1			

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FUNCTION TABLE

See note 1.

INP	OUTPUTS	
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

Note

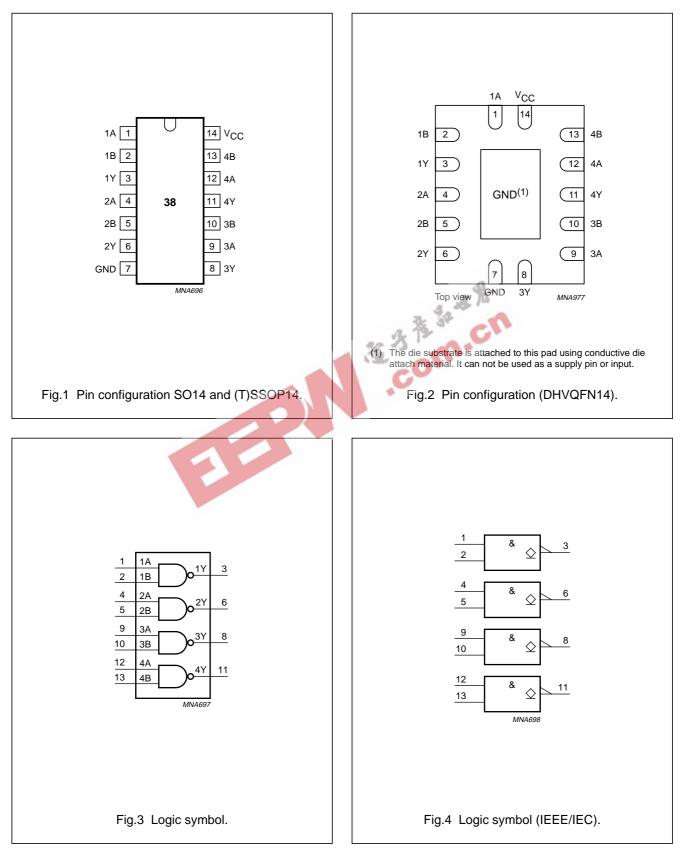
- 1. H = HIGH voltage level;
 - L = LOW voltage level:
 - Z = high-impedance OFF-state.

PINNING

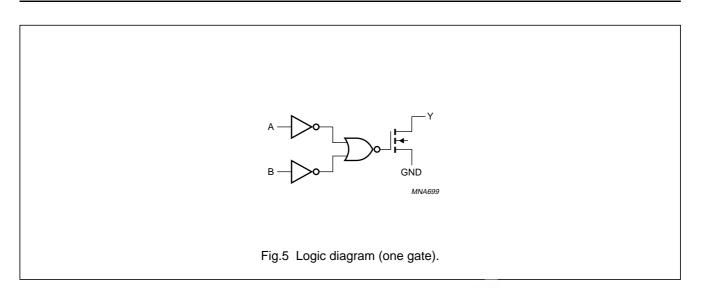
		J. D.
PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1B	data input
3	1Y	data output
4	2A	data input
5	2B	data input
6	2Y	data output
7	GND	ground (0 V)
8	3Y	data output
9	3A	data input
10	3B	data input
11	4Y	data output
12	4A	data input
13	4B	data input
14	V _{CC}	supply voltage

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage	for maximum speed performance	2.7	3.6	V
		for low-voltage applications	1.2	3.6	V
VI	input voltage	G	0	5.5	V
Vo	output voltage		0	5.5	V
T _{amb}	operating ambient temperature		-40	+125	°C
t _r , t _f	input rise and fall times	V _{CC} = 1.2 to 2.7 V	0	20	ns/V
		$V_{\rm CC} = 2.7$ to 3.6 V	0	10	ns/V

£....

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input diode current	V _I < 0	_	-50	mA
VI	input voltage	note 1	-0.5	+6.5	V
I _{OK}	output diode current	V _O < 0	-	-50	mA
Vo	output voltage	note 1	-0.5	+6.5	V
lo	output sink current	$V_{O} = 0$ to V_{CC}	-	50	mA
I _{CC} , I _{GND}	V _{CC} or GND current		-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation	$T_{amb} = -40$ to +125 °C; note 2	_	500	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. For SO14 packages: above 70 °C derate linearly with 8 mW/K.

For (T)SSOP14 packages: above 60 $^\circ\text{C}$ derate linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60 $^\circ\text{C}$ derate linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

OVMDO		TEST CONDITIONS					
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	- MIN.	TYP.	MAX.	UNIT
T _{amb} = -40) to +85 ° C; note 1			•			-1
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	_	_	V
			2.7 to 3.6	2.0	_	_	V
V _{IL}	LOW-level input voltage		1.2	-	_	GND	V
			2.7 to 3.6	-	_	0.8	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I _O = 100 μA	2.7 to 3.6	_	GND	0.20	V
		I _O = 12 mA	2.7	_	_	0.40	V
		I _O = 24 mA	3.0	-	_	0.55	V
ILI	input leakage current	$V_{I} = 5.5 V \text{ or GND}$	3.6		±0.1	±5	μA
I _{OZ}	3-state output OFF-state	$V_{I} = V_{IH} \text{ or } V_{IL};$	3.6	i⊈ ™	0.1	±10	μA
	current	$V_0 = 5.5 \text{ V or GND}$		20			
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_{O} = 0$	3.6	-	0.1	10	μA
ΔI_{CC}	additional quiescent supply	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0^{-1}$	2.7 to 3.6	-	5	500	μA
	current per input pin		6				
T _{amb} = -40) to +125 °C						
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	-	-	V
			2.7 to 3.6	2.0	_	-	V
V _{IL}	LOW-level input voltage		1.2	-	-	GND	V
			2.7 to 3.6	-	_	0.8	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I _O = 100 μA	2.7 to 3.6	-	_	0.3	V
		I _O = 12 mA	2.7	-	_	0.6	V
		I _O = 24 mA	3.0	-	_	0.8	V
ILI	input leakage current	$V_{I} = 5.5 V \text{ or GND}$	3.6	-	_	±20	μA
I _{OZ}	3-state output OFF-state	$V_{I} = V_{IH} \text{ or } V_{IL};$	3.6	-	_	±20	μA
	current	$V_0 = 5.5 V \text{ or GND}$					
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	3.6	-	_	40	μA
ΔI_{CC}	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0$	2.7 to 3.6	-	-	5000	μA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

 $GND = 0 V; t_r = t_f \le 2.5 ns.$

SYMBOL	PARAMETER	TEST COND	TIONS	MIN.	ТҮР	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T _{amb} = -40) to +85 °C; note 1						
t _{PZL}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	-	5.7	-	ns
			2.7	0.5	1.7	2.9	ns
			3.0 to 3.6	0.5	1.7 ⁽²⁾	3.0	ns
t _{PLZ}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	_	4.8	-	ns
			2.7	1.0	2.6	3.8	ns
			3.0 to 3.6	1.0	2.3 ⁽²⁾	3.6	ns
t _{sk(0)}	skew	note 3		-	-	1.0	ns
) to +125 °C						
t _{PZL}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	-	-	-	ns
			2.7	0.5	-	4.0	ns
			3.0 to 3.6	0.5	-	4.0	ns
t _{PLZ}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	-	-	-	ns
			2.7	1.0	_	5.0	ns
			3.0 to 3.6	1.0	-	4.5	ns
t _{sk(0)}	skew	note 3		-	-	1.5	ns

Notes

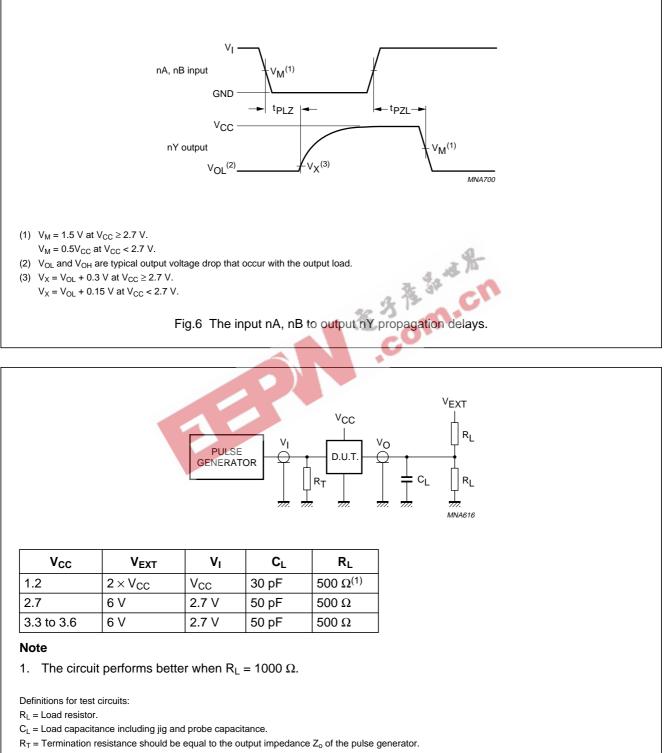
2. These typical values are measured at V_{CC} = 3.3 V.

3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

^{1.} All typical values are measured at $T_{amb} = 25$ °C.

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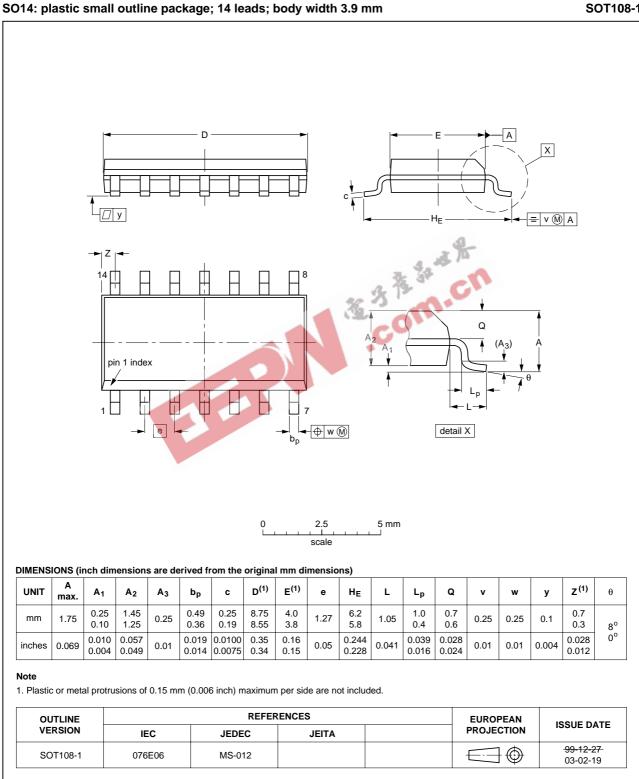
AC WAVEFORMS



 $t_r = t_f \le 2.5$ ns; when measuring f_{max} , there is no constraint on t_r , t_f with 50% duty factor.

Fig.7 Load circuitry for switching times.

PACKAGE OUTLINES



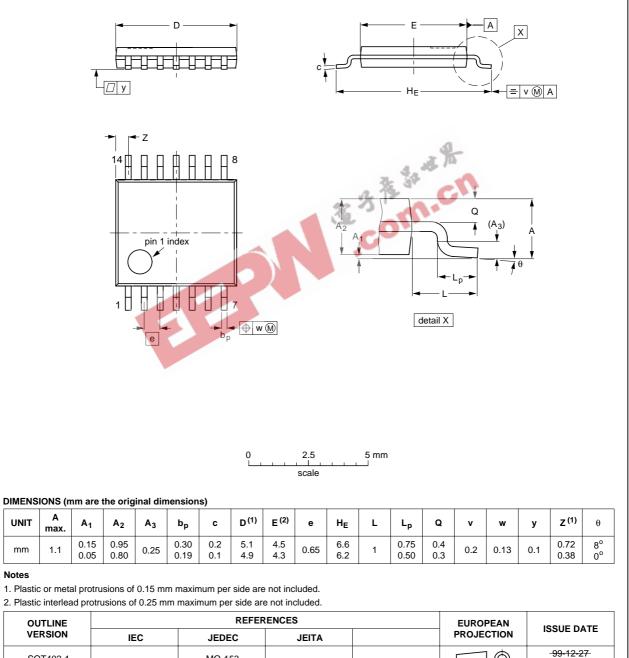
74LVC38A

SOT108-1

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm SOT337-1 Α D X - 🗇 у = v M A H_E is 3 is se s & cl -Z+ 14 4 $(A_3$ pin 1 index Lp detail X ⊢⊕w∭ bp е 2.5 5 mm 0 scale DIMENSIONS (mm are the original dimensions) Α D⁽¹⁾ E⁽¹⁾ Z⁽¹⁾ UNIT L Q θ Α₁ A_2 A_3 bp С е $H_{\rm E}$ Lp v w у max 0.21 0.38 0.20 1.03 8° 1.80 6.4 5.4 7.9 0.9 1.4 2 0.13 0.1 mm 0.25 0.65 1.25 0.2 0.05 1.65 0.25 0.09 6.0 5.2 7.6 0.63 0.7 0.9 0° Note 1. Plastic or metal protrusions of 0.25 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE **ISSUE DATE** VERSION PROJECTION IEC JEDEC JEITA 99-12-27 SOT337-1 MO-150 03-02-19

74LVC38A

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm SOT402-1 А D Х



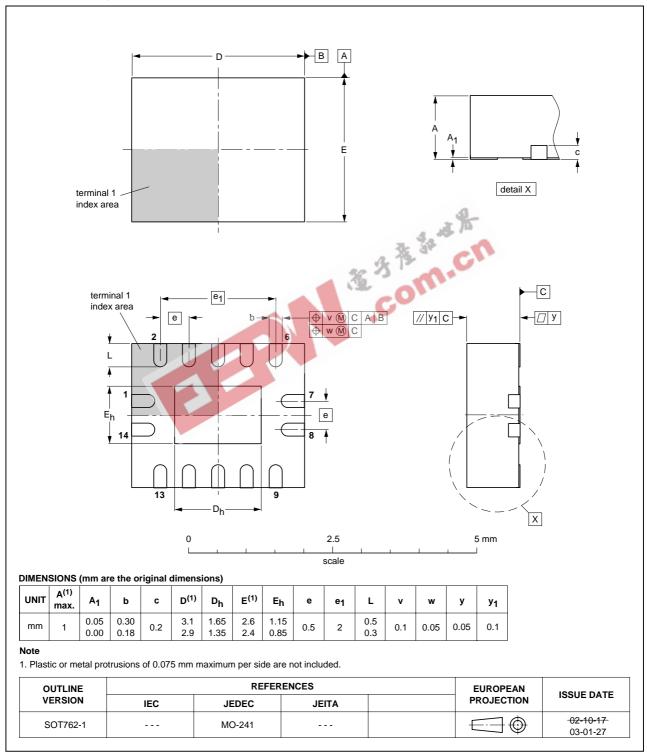
SOT402-1

03-02-18

MO-153

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

74LVC38A

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
111	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).
Notes	1	I	3. 15 15

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Printed in The Netherlands

R20/03/pp14

Date of release: 2004 Mar 22

Document order number: 9397 750 13029

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